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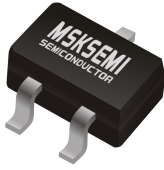
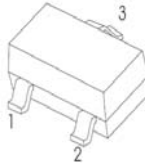


GDT



PLED

Product data sheet


SOT - 23


1. BASE
2. EMITTER
3. COLLECTOR

TRANSISTOR (NPN)
FEATURES

- High Collector-Emitter Voltage
- Complement to MMBTA94-MS

MARKING: 3D
MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

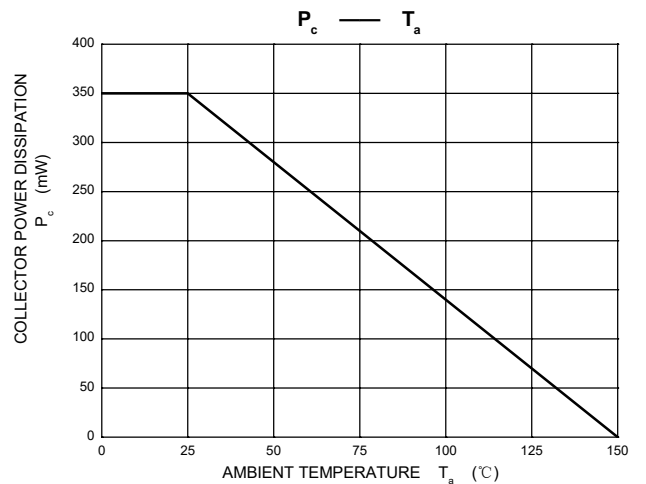
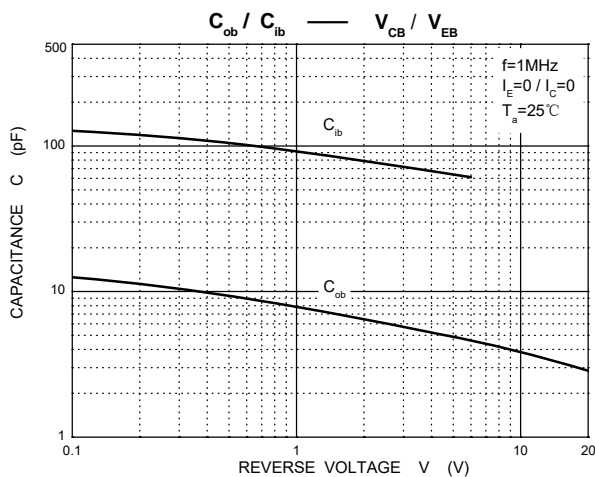
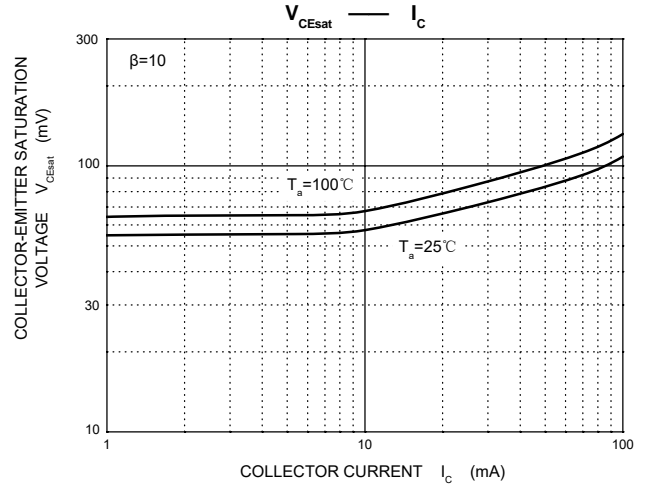
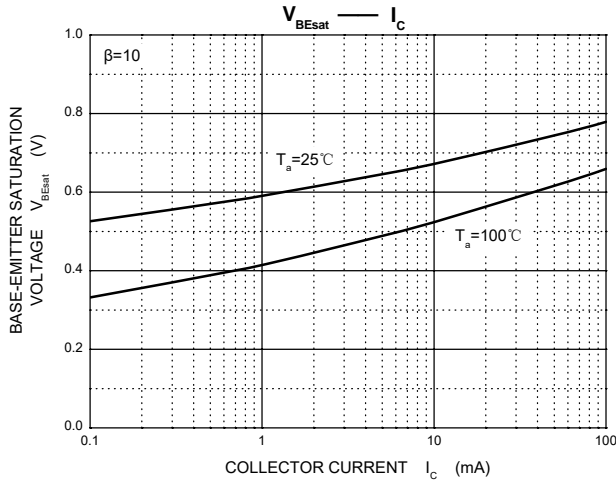
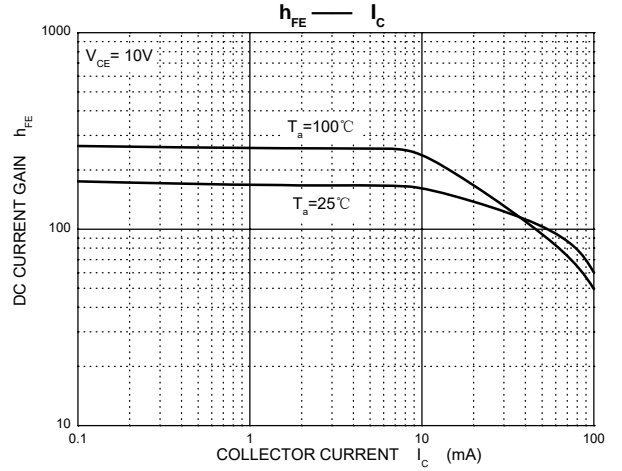
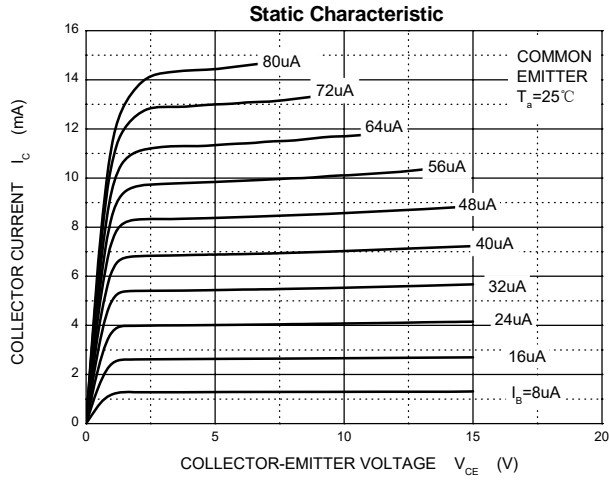
Symbol	Parameter	Value	Unit
V _{CB0}	Collector-Base Voltage	400	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current-Continuous	200	mA
I _{CA}	Collector Current -Pulsed	300	mA
P _C	Collector Power Dissipation	350	mW
R _{θJA}	Thermal Resistance From Junction To Ambient	357	°C/W
T _J , T _{STG}	Operation Junction and Storage Temperature Range	-55 ~ +150	°C

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

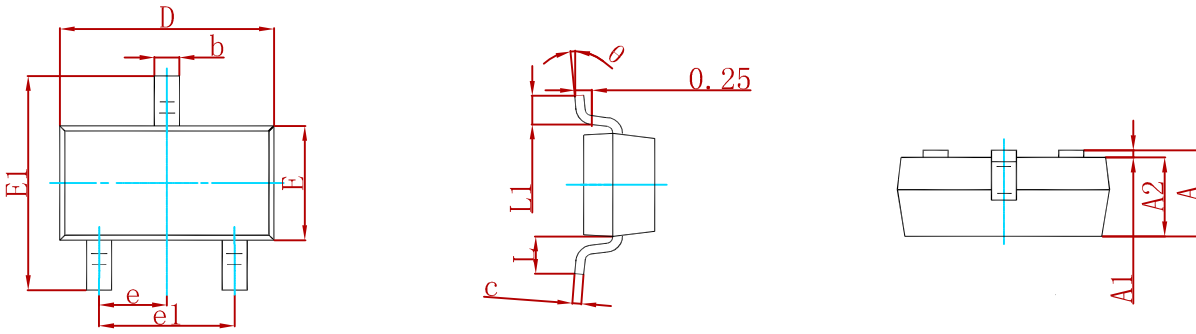
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =100μA, I _E =0	400			V
Collector-emitter breakdown voltage	V _{(BR)CEO} *	I _C =1mA, I _B =0	400			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =10μA, I _C =0	6			V
Collector cut-off current	I _{CBO}	V _{CB} =400V, I _E =0			0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =4V, I _C =0			0.1	μA
DC current gain	h _{FE(1)} *	V _{CE} =10V, I _C =1mA	40			
	h _{FE(2)} *	V _{CE} =10V, I _C =10mA	50		200	
	h _{FE(3)} *	V _{CE} =10V, I _C =50mA	45			
	h _{FE(4)} *	V _{CE} =10V, I _C =100mA	40			
Collector-emitter saturation voltage	V _{CE(sat)1} *	I _C =1mA, I _B =0.1mA			0.4	V
	V _{CE(sat)2} *	I _C =10mA, I _B =1mA			0.5	V
	V _{CE(sat)3} *	I _C =50mA, I _B =5mA			0.75	V
Base-emitter saturation voltage	V _{BE(sat)} *	I _C =10mA, I _B =1mA			0.75	V
Collector output capacitance	C _{ob}	V _{CB} =20V, I _E =0, f=1MHz			7	pF
Emitter input capacitance	C _{ib}	V _{EB} =0.5V, I _C =0, f=1MHz			130	pF
Transition frequency	f _T	V _{CE} =20V, I _C =10mA, f=30MHz	50			MHz

*Pulse test: pulse width ≤300μs, duty cycles ≤ 2.0%.

Typical Characteristics

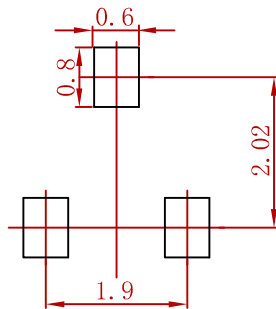


PACKAGE MECHANICAL DATA



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Suggested Pad Layout



- Note:
1. Controlling dimension: in millimeters.
 2. General tolerance: ± 0.05mm.
 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
MMBTA44-MS	SOT-23	3000

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